Modeling and Simulation for Solid-State Dewetting Problems



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Outline

Motivation

Sharp Interface models (SIMs)

- Isotropic surface energy
 - Anisotropic (weak/strong) surface energy
- Numerical methods & results in 2D

Phase field/Diffuse interface model

- Mathematical model
- Numerical methods
- Results in 3D
- Conclusion & future works

Patterned Ni(110) square patche



Wetting / Dewetting in Fluid Mechanics

Wetting – spread of a liquid on a substrate







Wetting — the rupture of a thin liquid film on a substrate







Solid-State Dewetting of Thin Films

Most thin films are metastable in as-deposited state & dewet to form particles



This occurs when the temperature is high enough for surface self diffusion, which can be well below the film's melting temperature

$$\gamma_{VS} = \gamma_{FS} + \gamma_{FV} \cos(\theta) - Young$$



- γ_{VS} : substrate free surface energy
- γ_{FV} : film free surface energy
- γ_{FS} : film-substracte interface energy



Dewetting on a flat substrate

[1] E. Jiran & C. V. Thompson, Journal of Electronic Materials, 19 (1990), pp. 1153-1160.[2] E. Jiran & C. V. Thompson, Thin Solid Films, 208 (1991), pp. 23-28.

Solid-State Dewetting Problems

Solid-state dewetting

- Is driven by capillarity effects
- Occurs through surface diffusion controlled mass transport
- Belongs to capillarity-controlled interface/surface evolution problems
- Surface diffusion + contact line migration
- Applications of dewetting of thin films
 - Play an improtant role in micorelectronics processing
 - A common method to produce nanoparticles
 - Catalyst for the growth of carbon nanotubes & semiconductor nanowires
- Recent experiments -- [1]
 - Geometric complexity, capillarity-driven instabilities, faceting
 - Crystalline anisotropy, corner-induced instabilities, pinch-off,
- **Wetting/dewetting in fluids:** TZ Qian, XP Wang&P Sheng; W. Ren&W E, ...

[1] J. Ye & C.V. Thompson, Acta Mater. 23 (2011), 1567; 59 (2011), 582; Appl. Phys. Lett. 97 (2010), 071904

Pinch-off







Dewetting Patterned Films

Patterned Ni(110) square patches



[1] J. Ye & C.V. Thompson, Phys. Rev. B, 82 (2010), 193408.

Effect of Size & Orientation of Pattern

Small square

Large square



[1] J. Ye & C.V. Thompson, Adv. Mater., 23 (2011), 1567.

Dewetting of Patterned Single-Crystal Films

Complex pattern formation







• Edge faceting

- Corner instability
- Mass shedding instability
- Rayleigh-like instability





Models and Methods for Dynamical Evolution

Sharp interface model

- Isotropic case
 - Model & power law --- Srolovitz & Safran JAP 86'
 - Marker particle method ---- Wong, Voorheers & Miksis 00'; Du etc JCP 10';
- Anisotropic (weakly and strongly) case
 - Model via thermodynamical variation Wang etc PRB 15'; Jiang etc 16', ...
 - Parametric finite element method (PFEM) -- Bao, Jiang, Wang & Zhao, 16'
- Kinetic Monte Carlo method Dufay & Pierre-Lious PRL 11'; Pierre-Louis etc, EPL&PRL 09
- **Discrete surface chemical potential method** –Dornel etc. PRB 06'; Klinger etc 12
- Phase field model ---Jiang, Bao Thompson & Srolovitz, Acta Mater. 12'
- Crystalline formulation method Cahn & Taylor 94'; Cater etc 95'; Kim etc 13'; Zucker etc 13'; Roosen etc 94'&98';

Sharp Interface Models (SIM)

X(s,t) = (x(s,t), y(s,t)) s -- arclength **Isotropic** surface energy--dynamics: $\frac{\partial X(s,t)}{\partial X(s,t)} = V_n \vec{n} \quad \text{with} \quad V_n = B \Delta_s \kappa$

Film Substrate

 $V_n = B \frac{\partial^2 \kappa}{\partial s^2}$ (in 2D)

 $\kappa = -\frac{\partial^2 y}{\partial s^2} \frac{\partial x}{\partial s} + \frac{\partial^2 x}{\partial s^2} \frac{\partial y}{\partial s}$

 $\gamma_{FV} = \gamma(\theta)$

Vapor

 $\vec{X}(s,t) = (x(s,t), y(s,t))$: moving front curve in 2D(surface in 3D)

- \vec{n} : unit outward normal direction
- $-V_n$: normal velocity of the moving interface
- -B : material constant
 - Δ_s : surface Laplacian or Laplace-Beltrami operator
 - κ : mean curvature of the surface

[1] D.J. Srolovitz & S.A. Safran, J. Appl. Phys., 60 (1986), 255.

[2] H. Wong et al., Acta Mater., 48 (2000), 1719.

 ∂t

SIM of Isotropic Surface Energy--Dynamics

$$\begin{array}{cccc} & \Gamma \colon X(s,t) = (x(s,t), y(s,t)) & s -- \text{ arclength} \\ & & \text{Boundary conditions (2D)} \\ & & - \text{ Contact point condition (BC1)} \\ & & y(x_c,t) = 0 \\ & & - \text{ Contact angle condition (BC2)} \\ & & & \\ & & \frac{\partial y}{\partial s}(x_c,t) \\ & & \frac{\partial x}{\partial s}(x_c,t) \\ & & - \text{ Zero-mass flux condition (BC3)} \end{array}$$



 $\cos \theta_i = \frac{\gamma_{VS} - \gamma_{FS}}{\gamma_{FV}} := \sigma$

∂ĸ $(x_c,t) = 0$

Total mass conservation of the film. No mass flux at the contact point-- no mass diffuses under the thin film at the film/substrate interface & any flux along the surface to the contact point simply moves the contact point along the substrate s.t. no flux remains

SIM for Isotropic Surface Energy – Equilibrium State

Total interfacial free energy

$$W(\omega) = \gamma_{FV} | \Sigma_{FV} | + \gamma_{FS} | \Sigma_{FS} | + \gamma_{VS} | \Sigma_{VS} |$$

Wall Energy

 γ_{FV} -- interfacial energy (density) $|\Sigma_{FV}|$ -- interface length (2D) or area (3D) **Equilibrium configuration**: min $W(\omega)$ subject to $\int_{\omega} d\omega = \text{constant}$



Wulff construction & Winterbottom construction

Existing Results for SIM of Isotropic Surface Energy

Asymptotic/mathematical results $x_c(t) \sim t^{2/5}$ $t \gg 1$, $0 \le \theta_i \ll 1$

- For 3D linearized problem (small angle) [1]:
- For equilibrium static problem -- linearized stability analysis -- [2]
- For dynamic nonlinear problem ????

Front-track approaches (marker particle methods) [3]:

- Results:
 - 2D with arclength works well
 - 3D with marker particles too tedious and low accuracy!!
 - Main difficulties
 - Fourth-order derivatives along the surfaces -- accuracy
 - Complex topological changes (pinch-off) complexity

[1] D.J. Srolovitz & S.A. Safran, J. Appl. Phys., 60 (1986), 247; 60(1986), 255.
 [2] H. Garcke, K. Ito & Y. Kohsaka, SIAM J. Math. Anal., 36 (2005), 1031-1056.
 [3] H. Wong, PW Voorhees, MJ Miksis, SH Davis, Acta Mater, 48 (2000), 1719.





SIM for Anisotropic Surface Energy

(via thermodynamical variation)

 $\Gamma := \vec{X}(s,t) = (x(s,t), y(s,t)) \qquad s -- \text{ arclength}$ Total interfacial free energy $W = \int \gamma_{FV}(\theta) d\Gamma + (\gamma_{FS} - \gamma_{VS})(x_c^r - x_c^l)$ Anisotropic surface energy $\gamma_{FV} = \gamma(\theta) = \gamma_0 [1 + \beta \cos(m\theta)],$ Thermo-dynamical variation: $\Gamma^{\epsilon} = \Gamma + \epsilon \varphi(s) \mathcal{N} + \epsilon \psi(s) \mathcal{T}$ Vapor Film x_c^r Substrate



$$m = 2, 3, 4, 6$$

 $\psi(s)$ is arbitrary & $\int_{0}^{L} \varphi(s) ds = 0$

$$\Gamma^{\varepsilon}(t) = (x^{\varepsilon}(s,t), y^{\varepsilon}(s,t))$$
$$= (x(s,t) + \varepsilon u(s,t), y(s,t) + \varepsilon v(s,t))$$

$$u(s,t) = x_s(s,t)\psi(s) - y_s(s,t)\phi(s)$$

$$v(s,t) = x_s(s,t)\phi(s) + y_s(s,t)\psi(s)$$

$$v(0,t) = v(L,t) = 0 \quad \& \quad |A(\Gamma^{\varepsilon}) - A(\Gamma)| \le C_0 \varepsilon^2$$

SIM for Anisotropic Surface Energy

(via thermodynamical variation)

Calculate first variation of the energy functional $W = \int_{\Gamma} \gamma_{FV}(\theta) d\Gamma + (\gamma_{FS} - \gamma_{VS})(x_c^r - x_c^l)$ $W^{\varepsilon} = \int \gamma_{FV}(\theta^{\varepsilon}) d\Gamma + (\gamma_{FS} - \gamma_{VS}) [(x_c^r + \varepsilon u(L, t)) - (x_c^l + \varepsilon u(0, t))]$ $\frac{dW^{\varepsilon}}{d\varepsilon}\bigg|_{\varepsilon=0} = \lim_{\varepsilon \to 0} \frac{W^{\varepsilon} - W}{\varepsilon} = \int_{0}^{L} (\gamma(\theta) + \gamma''(\theta)) \kappa \varphi ds + f(\theta_{c}^{r})u(L,t) - f(\theta_{c}^{l})u(0,t)$ $\mu := \frac{\delta W}{\delta \Gamma} = (\gamma(\theta) + \gamma''(\theta))\kappa, \quad \frac{\delta W}{\delta x^r} = f(\theta) \Big|_{\theta = \theta_c^r}, \quad \frac{\delta W}{\delta x^l} = -f(\theta) \Big|_{\theta = \theta_c^l}$ $f(\theta) := \gamma(\theta) \cos \theta - \gamma'(\theta) \sin \theta - \gamma_0 \cos \theta_i, \quad \cos \theta_i = \sigma := \frac{\gamma_{VS} - \gamma_{FS}}{\gamma_{VS} - \gamma_{FS}}$

[1] Wang, Jiang, Bao & Srolovitz, Phys. Rev. B, 2015.

SIM for Weakly Anisotropic Surface Energy

 $\gamma_{\scriptscriptstyle FV} = \gamma(\theta)$

Vapor

Wang, Jiang, Bao, Srolovitz, PRB 15') Film $\frac{\partial \vec{X}(s,t)}{\partial t} = V_n \vec{n}, \quad \text{with} \quad V_n = B \frac{\partial^2 \mu}{\partial s^2}$ Substrate $\mu(\theta) = B(\gamma(\theta) + \gamma''(\theta))\kappa$ θ_c^r – – Dynamical contact angle θ_i ----Isotropic Young contace angle **Weighted Boundary** conditions - Contact point condition (BC1): $y(x_c^r, t) = 0$ - Relaxed contact angle condition (BC2)[1]: $\frac{dx_c'(t)}{dt} = -\eta \frac{\delta W}{\delta x'} = -\eta f(\theta_c^r),$ - Zero-mass flux condition (BC3): $\partial_s \mu(x_c^r, t) = 0$ ♦ Anisotropic Young equation $\eta \to \infty$ $\gamma(\theta) \equiv \gamma_0$ $\gamma(\theta)\cos\theta - \gamma'(\theta)\sin\theta - \gamma_0\cos\theta_i = 0 \implies \cos\theta = \cos\theta_i$ [1] Ren, E, Phys. Fluid, 2007&2011; Ren, Hu & E, Phys Fluid, 2010.

 Γ : $\vec{X}(s,t) = (x(s,t), y(s,t))$ s -- arclength

Dynamical Properties

L(t)

$$A(t) = \int_{0}^{L} y \partial_{s} x \, ds \Rightarrow A(t) \equiv A(0)$$

$$A(t) = \int_{0}^{L} y \partial_{s} x \, ds \Rightarrow A(t) \equiv A(0)$$

$$V(t) = \int_{0}^{L(t)} \gamma_{FV}(\theta) ds + (\gamma_{FS} - \gamma_{VS})(x_{c}^{r} - x_{c}^{l}) \Rightarrow W'(t) = -\int_{0}^{L(t)} (\partial_{s} \mu)^{2} ds + \mu \partial_{s} \mu \Big|_{s=0}^{s=L(t)}$$

$$+ \frac{dx_{c}^{r}(t)}{dt} f(\theta) \Big|_{\theta = \theta_{c}^{r}} - \frac{dx_{c}^{l}(t)}{dt} f(\theta) \Big|_{\theta = \theta_{c}^{l}} = -\int_{0}^{L(t)} (\mu_{s})^{2} ds - C \left[\left(\frac{dx_{c}^{r}(t)}{dt} \right)^{2} + \left(\frac{dx_{c}^{l}(t)}{dt} \right)^{2} \right] \leq 0$$

Weakly anisotropic case:

$$\gamma(\theta) + \gamma''(\theta) > 0 \quad \Leftrightarrow \quad 0 \le \beta < \frac{1}{m^2 - 1}$$

Strongly Anisotropic Case

Strongly anisotropic case

Case I:

$$\beta > \frac{1}{m^2 - 1} \Rightarrow \gamma(\theta) + \gamma''(\theta)$$
 change sign

• ill-posedness

Multiple solution of the anisotropic Young equation

$$\gamma(\theta)\cos\theta - \gamma'(\theta)\sin\theta - \gamma_0\cos\theta_i = 0$$

Regularize the total energy

Case II: Surface energy is not smooth $\gamma(\theta) \notin C^2 \Rightarrow \gamma_{\varepsilon}(\theta) \in C^2$ • A typical example

$$\gamma(\theta) = \sqrt{\left|\cos\theta\right| + \left|\sin\theta\right|} \Longrightarrow \gamma_{\varepsilon}(\theta) = \sqrt{\left(\varepsilon + \cos^2\theta\right)^{1/2} + \left(\varepsilon + \sin^2\theta\right)^{1/2}}$$

Regularize (or smooth) the surface energy density

Strongly Anisotropic Surface Energy

Van

F:
$$\ddot{X}(s,t) = (x(s,t), y(s,t))$$
 s -- arclength
Regularized interfacial free energy
 $W_{\varepsilon} = \int \gamma_{FV}(\theta) d\Gamma + (\gamma_{FS} - \gamma_{VS})(x_c^r - x_c^l) + \frac{\varepsilon^2}{2} \int_{\Gamma} \kappa^2 d\Gamma$
Calculate first variation of the energy functional
 $\mu_{\varepsilon} := \frac{\delta W_{\varepsilon}}{\delta \Gamma} = (\gamma(\theta) + \gamma''(\theta))\kappa - \varepsilon^2 \left[\partial_{ss}\kappa + \frac{\kappa^3}{2}\right],$
 $\frac{\delta W_{\varepsilon}}{\delta x_c^r} = f_{\varepsilon}(\theta)|_{\theta = \theta_c^r}, \quad \frac{\delta W_{\varepsilon}}{\delta x_c^l} = -f_{\varepsilon}(\theta)|_{\theta = \theta_c^l}, \qquad \cos \theta_i = \sigma := \frac{\gamma_{VS} - \gamma_{FS}}{\gamma_0}$
 $f_{\varepsilon}(\theta) := \gamma(\theta) \cos \theta - \gamma'(\theta) \sin \theta - \gamma_0 \cos \theta_i + \varepsilon^2 \left[\frac{\kappa(\theta)^2}{2} \cos \theta - \partial_s \kappa(\theta) \sin \theta\right]$
[1] J. Lowengrub, A. Voigt,
[2] Jiang, Wang, Zhao, Srolovitz & Bao, Script. Mater., 16'.

SIM for Strongly Anisotropic Surface Energy

Z: X(s,t) = (x(s,t), y(s,t)) s -- arclength $\gamma_{FV} = \gamma(\theta)$ Vapor The Model (Jiang, Wang, Zhao, Srolovitz, Bao, 16') Film $\frac{\partial \vec{X}(s,t)}{\partial t} = V_n \vec{n}, \quad \text{with} \quad V_n = B \frac{\partial^2 \mu_{\varepsilon}}{\partial s^2} \qquad \frac{\gamma_{vs}}{a} \sum_{x_c} V_{vs}$ $\mu_{\varepsilon}(\theta) = B(\gamma(\theta) + \gamma''(\theta))\kappa - \varepsilon^2 \left[\partial_{ss}\kappa + \frac{\kappa^3}{2}\right] \quad \theta_c^r - \text{Dynamical contact angle} \\ \theta_i - \text{Isotropic Young contace angle}$ **Boundary** conditions - Contact point condition (BC1): $y(x_c^r, t) = 0$ - Relaxed contact angle condition (BC2): $\frac{dx_c^r(t)}{dt} = -\eta \frac{\delta W}{\delta x^r} = -\eta f_{\varepsilon}(\theta_c^r),$ – Zero-curvature condition (BC3): $\kappa(x_c^r, t) = 0$ - Zero-mass flux condition (BC4): $\partial_{s} \mu(x_{c}^{r}, t) = 0$

Parametric Finite Element Method (PFEM)

Weakly anisotropic case

 $\kappa \vec{n} = -\partial_{ss} \vec{X}(s,t)$

- Mathematical model and variational form

- $(\partial_{t}\vec{X}(s,t)) \bullet \vec{n} = B\partial_{ss}\mu \qquad \qquad \int_{C} (\partial_{t}\vec{X}(s,t)) \bullet \vec{n} \phi dp + \int_{C} B\partial_{s}\mu \partial_{s}\phi dp = 0, \quad \phi \in H_{0}^{1}$ $\mu(\theta) = (\gamma(\theta) + \gamma''(\theta))\kappa \Leftrightarrow \qquad \int_{C} [\mu(\theta) - (\gamma(\theta) + \gamma''(\theta))\kappa] \phi dp = 0, \quad \phi \in H^{1}$
 - $\int_{C} \kappa \vec{n} \cdot \vec{\eta} dp + \int_{C} \partial_{s} \vec{X}(s,t) \cdot \partial_{s} \vec{\eta} dp = 0, \qquad \vec{\eta} \in (H_{0}^{1})^{2}$
 - Boundary conditions $y(x_c^r, t) = 0$, $\frac{dx_c^r(t)}{dt} = -\eta f(\theta_c^r)$ - Finite element discretization via piecewise polynomials Kef: [1] J.W. Barratt, H. Garcke & R. Nurnberg, J. Comput. Phys., 2007; SISC (2007); 2012. [2] W. Bao, W. Jiang & Q. Zhao, 2015.

$L = 5, \beta = 0, \sigma = \cos(3\pi/4)$



Isotropic surface energy and short

$L = 5, m = 4, \beta = 0.06, \sigma = \cos(3\pi/4)$

Weakly anisotropic surface energy & short

$$L = 60, m = 4, \beta = 0.06, \sigma = \cos(5\pi/6)$$

Weakly anisotropic surface energy & long for pinch-off

 $L = 5, m = 4, \beta = 0.2, \sigma = \cos(3\pi/4)$

Strongly anisotropic surface energy & short

Extension to Curved Substrate

 $L = 5, \beta = 0, \sigma = \cos(\pi/3)$



Extension to Curved Substrate

 $L = 5, \beta = 0, \sigma = \cos(\pi/3)$



 $y = 4\sin(x/4)$

Extension to Curved Substrate





(a1)







Experiment (Ye, et. Al, PRB, 10')

Simulation

Phase Field/Diffuse Interface Model

Phase field models --- S. Allen & J.W. Cahn (1975—79), J.W. Cahn & J. E. Hilliard (1958);
 G.J. Fix (1983), J.S. Langer (1986), L.Q. Chen (2002); C.M. Elliott, X.F. Chen, J. Shen, Q. Du, J. Lowengrub, A. Voigt, Q. Wang, G. Forest, XB Feng, PW Zhang, A.A. Lee A. Munch & E. Suli, ...

- Introduce a phase function& write down the energy
- By variation Allen-Cahn or Cahn-Hilliard equations
- Applications in materials simulation: solidification; viscous fingering; fracture; solid-state nucleation; dislocation dynamics,

Advantages

- Interface/surface capturing method Eulerian coordinates
- Easy extension from 2D to 3D
- Naturally capture complex topological changes

Problem Set-up



Figure: A schematical illustration of the problem set-up.

Phase Field Model



Phase Field Model

Film/vapor phase energy — Ginzburg-Landau free energy

 $f_{FV}(\phi, \nabla \phi) = \underbrace{\lambda}_{\text{mixing constant}} \left[\frac{\varepsilon}{2} \underbrace{|\nabla \phi|^2}_{\text{film/vapor energy}} + \frac{1}{\varepsilon} \underbrace{F(\phi)}_{\text{interface energy}} \right], \qquad F(\phi) = (\phi^2 - 1)^2$

- Convergence – L. Modica & S. Mortola, Boll. Un. Mat. Ital. A, 14 (1977), 526. If $\lambda = \frac{3\sqrt{2}}{4}\gamma_{FV} \implies W_{FV}^{\varepsilon} \rightarrow \gamma_{FV} |\Sigma_{FV}|$ Wall energy must satisfy

- At homogeneous vapor phase $\phi = -1 \Rightarrow f_W(\phi) = \gamma_{VS} \& f'_W(\phi) = 0$ - At homogeneous film phase $\phi = 1 \Rightarrow f_W(\phi) = \gamma_{FS} \& f'_W(\phi) = 0$

$$f_{W}(\phi) = \frac{\gamma_{VS} + \gamma_{FS}}{2} - \frac{\phi(3 - \phi^{2})}{4} (\gamma_{VS} - \gamma_{FS})$$

Phase Field Model

Cahn-Hilliard equation with function-dependent mobility $\begin{cases}
\frac{\partial \phi}{\partial t} = \nabla \cdot (M \nabla \mu) & \text{in } \Omega \quad \text{with} \quad M = (1 - \phi^2)^2 \\
\mu = \phi^3 - \phi - \varepsilon^2 \Delta \phi
\end{cases}$

With BCS(Jiang, Bao, Thompson & Srolovitz, Acta Mater., 12')

- On wall boundary $\Gamma_W \qquad \varepsilon \frac{\partial \phi}{\partial \vec{n}} + \frac{f_W(\phi)}{\lambda} = 0 \quad \& \quad \cos \theta_s = \frac{\gamma_{VS} - \gamma_{FS}}{\gamma_{FV}}$ $\varepsilon \frac{\partial \phi}{\partial \vec{n}} + \frac{\sqrt{2}}{2} (\phi^2 - 1) \cos \theta_s = 0 \quad \& \quad \frac{\partial \mu}{\partial \vec{n}} = 0$

- On other boundaries $\Gamma_0 \cup \Gamma_1 = \partial \Omega \setminus \Gamma_W \frac{\partial \phi}{\partial \vec{n}} = 0$ & $\frac{\partial \mu}{\partial \vec{n}} = 0$ Recent debate on proper mobility for surface diffusion – A.A. Lee, A. Munch & E

Suli, APL 15' & 16'; A. Voigt, APL 16',

Numerical Method

Stabilized semi-implicit method $\frac{\phi^{n+1} - \phi^n}{\tau} = A\varepsilon^2 \Delta^2 (\phi^n - \phi^{n+1}) + S\Delta(\phi^{n+1} - \phi^n) + \nabla \cdot (M^n \nabla \mu^n)$ $\mu^n = (\phi^n)^3 - \phi^n - \varepsilon^2 \Delta \phi^n, \qquad M^n = 1 - (\phi^n)^2$

- A and S are two stabilizing constants
 - *x*-direction by cosine pseudospectral method
 - y-direction by finite difference/finite element
- 1st order in time & can be upgraded to 2nd
- Can be solved efficiently at every step & Extension to 3D is easy

[1] W. Jiang, W. Bao, C.V. Thompson &D. J. Srolovitz, Acta Mater. 60(2012), 5578.

[2] J.Z. Zhu, L.Q. Chen, J Shen & V. Tikare, Phys. Rev. E, 60 (1999), 3564.

[2] J. Shen & X.F. Yang, SIAM J. Sci. Comput., 32 (2010), 1159.

3D Results I -- Square $\theta_s = 5\pi/6$



3D Results II – Pinch-off $\theta_s = 5\pi/6$



3D Results III – Large-Thin Square



3D Results – Comparison with Experiment







Computational Results

0.15



Experimental Results

Conclusion & Future Works

Conclusion

- Propose sharp interface model (SIM) for anisotropic surface energy
- Propose phase field model Cahn-Hilliard Eq. with function-dependent mobility
- Design stable, efficient & accurate numerical methods
- Test parameters regimes & simulate 2D & 3D results
- Compare qualitatively with experimental / asymptotic results

E Future works

- Phase field model with anisotropic surface energy
- Sharp interface model in 3D and/or rough substrate
- Investigate role of different surface energy anisotropy & regularization
 Develop adaptive & parallel pumerical method
 - Develop adaptive & parallel numerical method
 - Mathematical analysis of the models
 - Compare with experiments quantitatively & guide new experiments